2N2222

Low Power Bipolar Transistors

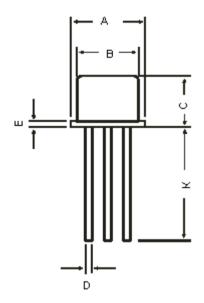




Features:

- NPN Silicon Planar Switching Transistors.
- Switching and Linear application DC and VHF Amplifier applications.

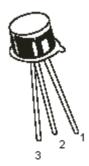
TO-18 Metal Can Package



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Dimensions	Minimum	Maximum	
А	5.24	5.84	
В	4.52	4.97	
С	4.31	5.33	
D	0.40	0.53	
Е	-	0.76	
F	-	1.27	
G	-	2.97	
Н	0.91	1.17	
J	0.71	1.21	
K	12.70	-	
L	45°		

Dimensions : Millimetres



Pin Configuration:

- 1. Emitter
- 2. Base
- 3. Collector



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Absolute Maximum Ratings (T_a = 25°C unless specified otherwise)

Description	Symbol	2N2222	Unit	
Collector Emitter Voltage	V _{CEO}	30		
Collector Base Voltage	V _{CBO}	60	V	
Emitter Base Voltage	V _{EBO}	5		
Collector Current Continuous	I _C	800	mA	
Power Dissipation at T _a = 25°C Derate above 25°C	P _D	500 2.28	mW mW/°C	
Power Dissipation at T _C = 25°C Derate above 25°C	' D	1.2 6.85	W mW/°C	
Operating and Storage Junction Temperature Range	T _J , Tstg	-65 to +200	°C	

Electrical Characteristics ($T_a = 25$ °C unless specified otherwise)

Description Symbol	Symbol Test Condition	Value		Unit	
	rest Condition	Minimum	Maximum	Offic	
Collector Emitter Breakdown Voltage	BV _{CEO}	I _C = 10mA, I _B = 0	30	-	
Collector Base Breakdown Voltage	BV _{CBO}	$I_{C} = 10\mu A, I_{E} = 0$	60	-	V
Emitter Base Breakdown Voltage	V_{EBOf}	$I_E = 10\mu A, I_C = 0$	5	-	
Collector Leakage Current	I _{CBO}	$V_{CB} = 50V, I_{E} = 0$ $V_{CB} = 50V, I_{E} = 0$ $T_{a} = 150^{\circ}C$	-	10 10	nA μA
Collector Emitter Saturation Voltage	*V _{CE (Sat)}	I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA	-	0.4 1.6	V
Base Emitter Saturation Voltage	*V _{BE (Sat)}	I _C = 150mA, I _B = 15mA I _C = 500mA, I _B = 50mA	0.6	1.3 2.6	V







Electrical Characteristics ($T_a = 25$ °C unless specified otherwise)

Parameter Symbo	Sumbal Test Condition	2N2222		Unit	
	Symbol	ol Test Condition	Minimum	Maximum	
DC Current Gain	h _{FE}	I_{C} = 0.1mA, V_{CE} = 10V* I_{C} = 1mA, V_{CE} = 10V I_{C} = 10mA, V_{CE} = 10V* I_{C} = 150mA, V_{CE} = 1V* I_{C} = 150mA, V_{CE} = 1V* I_{C} = 500mA, V_{CE} = 10V*	35 50 75 50 100 30	300	-
Dynamic Characteristics					l
Transition Frequency	f _t	I _C = 20mA, V _{CE} = 20V f = 100MHz	250	-	MHz
Output Capacitance	C _{ob}	$V_{CB} = 10V, I_{E} = 0$ f = 100kHz	-	8	
Input Capacitance	C _{ib}	$V_{EB} = 0.5V, I_{C} = 0$ f = 100kHz	-	30	- pF
Switching Characteristics	1			1	1
Delay Time	t _d	I _C = 150mA,I _{B1} = 15mA	-	10	
Rise Time	t _r	V _{CC} = 30V, V _{BE (off)} = 0.5V	-	25	ne
Storage Time	t _s	I _C = 150mA, I _{B1} = 15mA	-	225	ns
Fall Time	t _f	I _{B2} = 15mA, V _{CC} = 30V	-	60	

^{*}Pulse Condition: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

Part Number Table

Package	Part Number
TO-18	2N2222



2N2222

Low Power Bipolar Transistors



Notes:

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